

Features:

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$	3090 A
V_{RRM}	3100~4200 V
I_{FSM}	35 kA
I^2t	6125 10³A²S



SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T _J (°C)	VALUE			UNIT
					Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	T _C =85°C	160			3090	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms		160	3100		4200	V
I_{RRM}	Repetitive peak current	at V _{RRM}		160			160	mA
I_{FSM}	Surge forward current	10ms half sine wave		160			35	kA
I^2t	I ² t for fusing coordination	V _R =0.6V _{RRM}					6125	A ² s*10 ³
V_{FO}	Threshold voltage			160			0.88	V
r_F	Forward slope resistance						0.15	mΩ
V_{FM}	Peak forward voltage	I _{FM} =4000A, F=35kN		160			1.48	V
Q_{rr}	Recovery charge	I _{FM} =2000A, tp=2000μs, di/dt=-20A/μs, V _R =50V		160		5700		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 35kN					0.012	°C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.003		
F_m	Mounting force				30		40	kN
T_{stg}	Stored temperature				-40		160	°C
W_t	Weight					820		g
Outline								

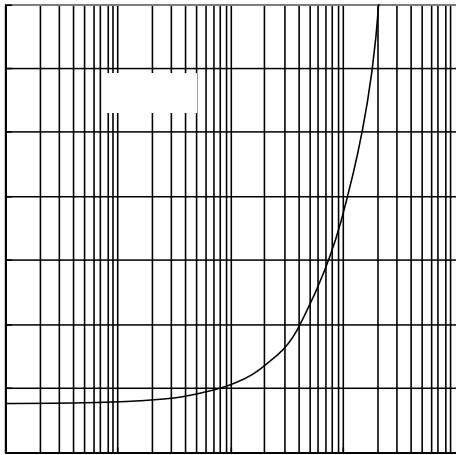


Fig.1

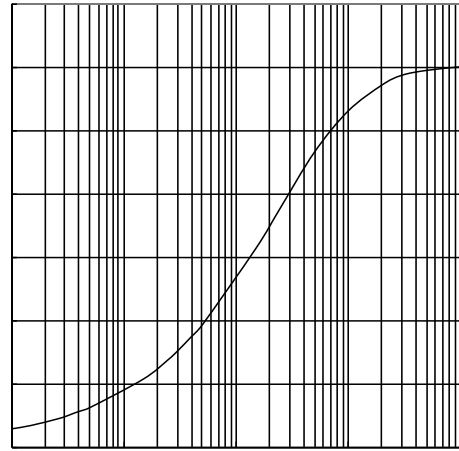


Fig.2

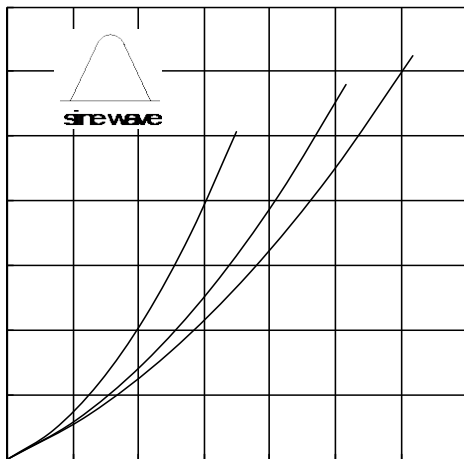


Fig.3

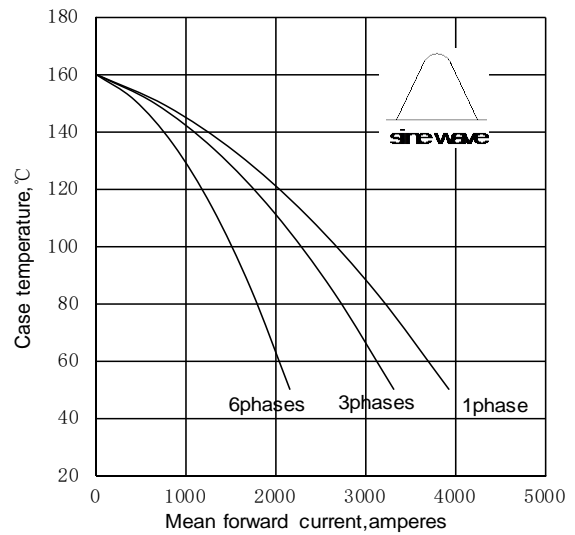


Fig.4

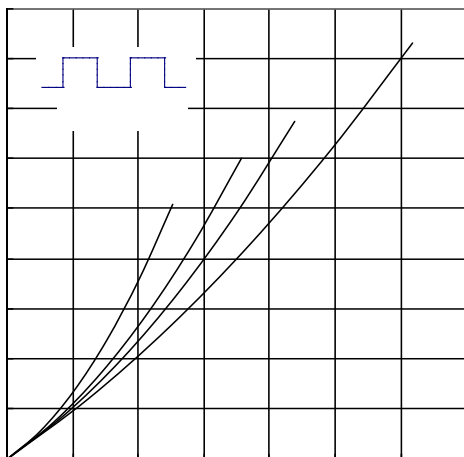


Fig.5

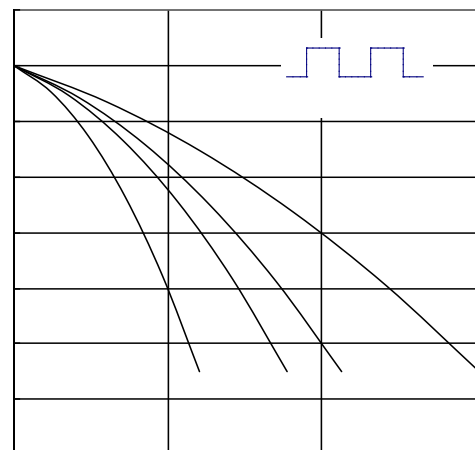


Fig.6

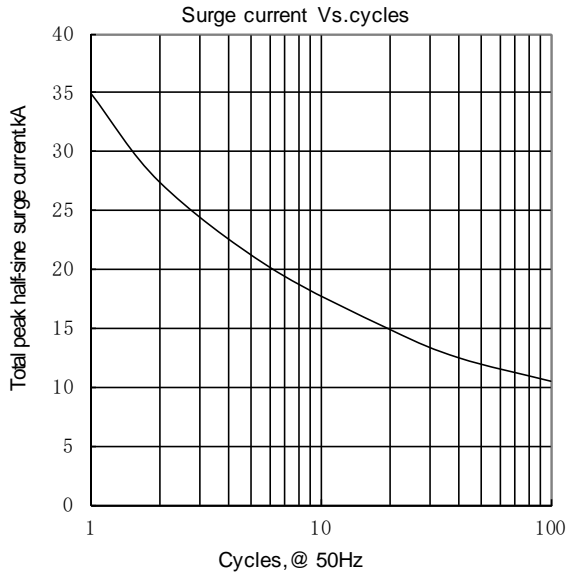


Fig.7

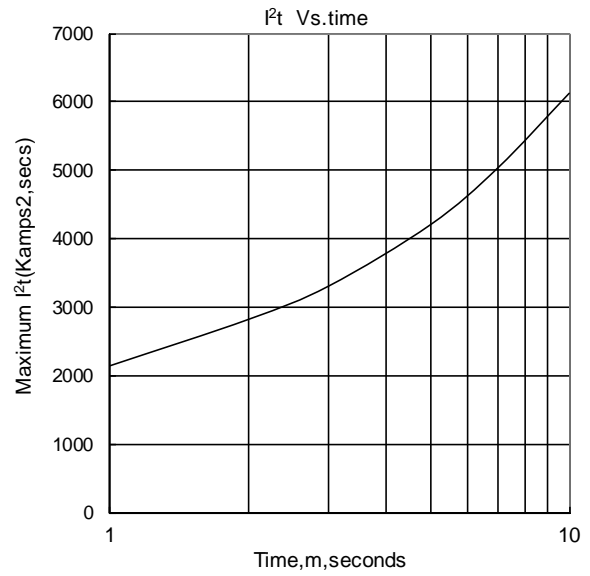


Fig.8

Outline:

